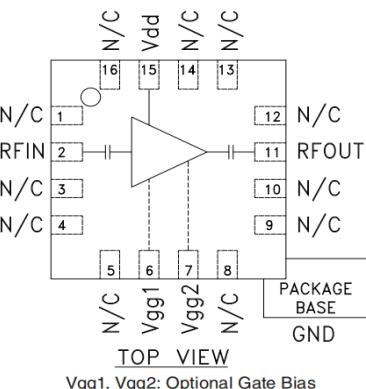


Performance characteristics

- Frequency band: 6GHz ~ 20GHz
- Gain: 14.5 dB
- Output P_{1dB}: 20.5 dBm
- Output saturation power: 21dBm
- Power supply: + 5V @ 113mA
- Package size: 3.0 mm × 3.0 mm

Typical application

- Base station communication
- Wireless infrastructure
- Automotive electronics
- Instruments and meters

Functional Diagram**Overview**

The CW441SP3 is a GaAs MMIC driver amplifier with a frequency range of 6GHz to 20GHz and an in-band gain of 14.5 dB. The chip is powered by + 5V single power supply.

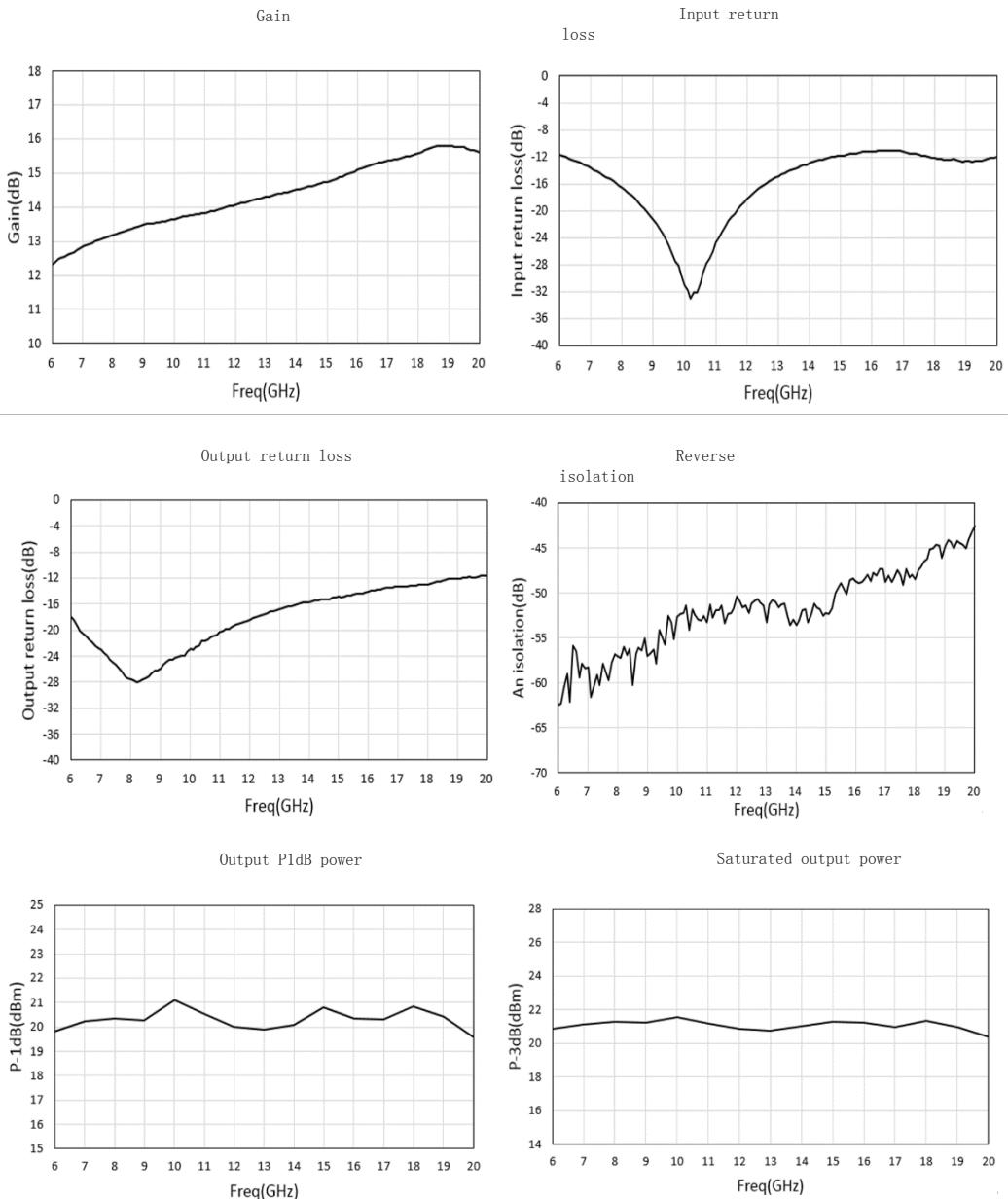
Electrical performance table (TA=+25 °C, VD=+5V)

Indicators	Minimum value	Typical value	Maximum value	Unit
Frequency range		6 ~ 20		GHz
Gain	12	14.5	-	dB
Input return loss	10	16	-	dB
Output return loss	10	18	-	dB
Output P _{1dB}	19	20.5	-	dBm
Saturated output power	20	21	-	dBm
Additional power efficiency	-	21	-	%
Operating current	-	113	-	mA

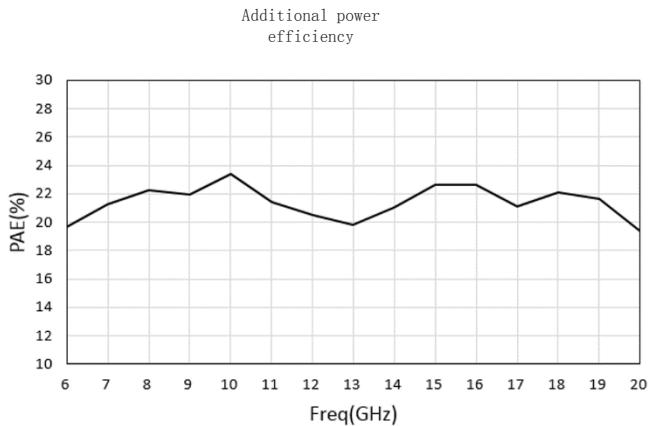
Use parameters (exceeding any of the above maximum limits may cause permanent damage)

Input power	10dBm
Voltage	+ 7V
Storage temperature	-65 °C-150 °C
Operating temperature	-55 °C-85 °C

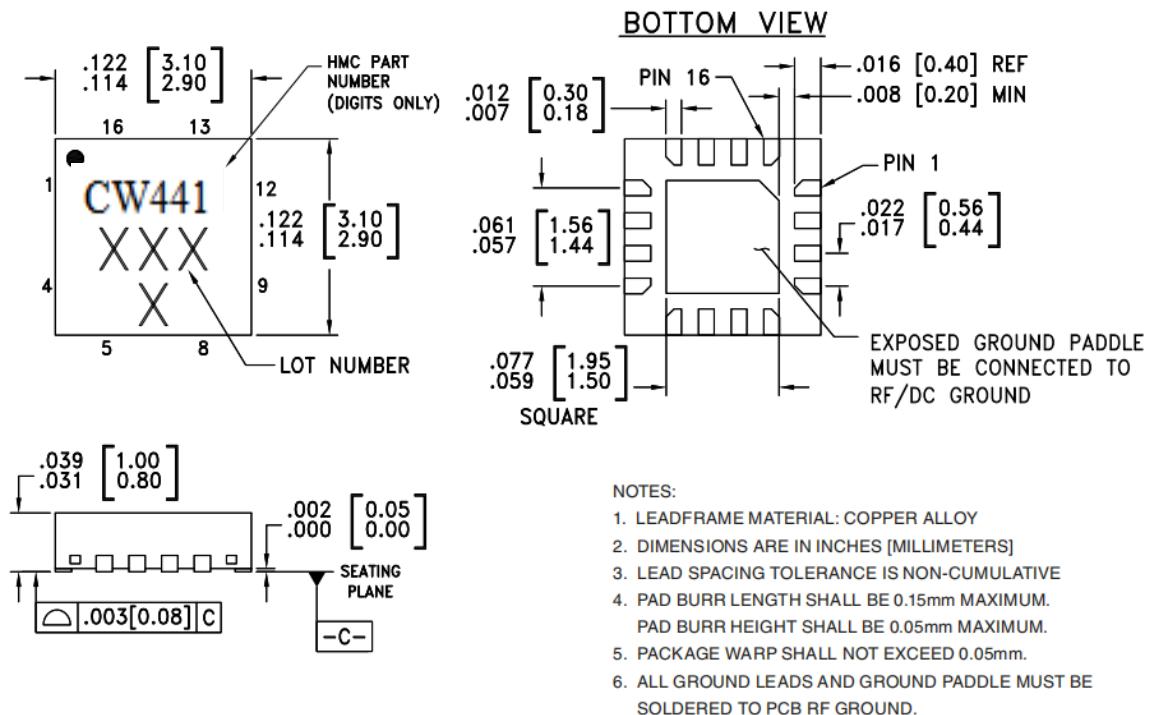
Test curve



Test curve



Outline Drawing



PIN Description

Pin Number	Function	Description	Interface Schematic
1, 3-5, 8-10, 12-14, 16	N/C	This pin may be connected to RF/DC ground.	
2	RFIN	This pin is AC coupled and matched to 50 Ohms.	
6, 7	Vgg1, Vgg2	Optional gate control for amplifier. If left open, the amplifier will run at standard current. Negative voltage applied will reduce current.	
11	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
15	Vdd	Power Supply Voltage for the amplifier. An external bypass capacitor of 100 pF is required.	
	GND	Package bottom must be connected to RF/DC ground.	